

Supporting Information:

Accurate Excitation Energies of Point Defects

from Fast Particle-Particle Random

Approximation Calculations

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1 Details about geometry optimizations

We obtained the ground-state equilibrium atomic geometries of point defects in diamond and 4H-SiC using density functional theory^{S1,S2} (DFT) and the plane-wave pseudopotential method, as implemented in the Quantum ESPRESSO package,^{S3,S4} by minimizing the nuclear forces below the threshold of 0.01 eV Å⁻¹. Our study involved unrestricted Kohn-Sham DFT calculations for the triplet ground states, specifically the ³A₂ ground state of NV⁻ in diamond, *kk*-VV⁰ in 4H-SiC, and the ³A_{2g} ground state of SiV⁰ in diamond. We used SG15 ONCV norm-conserving pseudopotentials^{S5,S6} and the PBE^{S7} functional with the plane-wave energy cutoff setting to 60 Ry.

2 Excitation energies of defects obtained from ppRPA

Table S1: Vertical excitation energies of NV⁻ in diamond obtained from ppRPA@PBE and ppRPA@B3LYP with the supercell model containing 63 atoms. (*O*, *V*) means that *O* occupied orbitals and *V* virtual orbitals were used in the active space. The geometry of the ³A₂ ground state and cc-pVDZ basis set were used. All values are in eV.

	ppRPA@PBE			ppRPA@B3LYP		
	¹ E	¹ A ₁	³ E	¹ E	¹ A ₁	³ E
(10,10)	0.56	1.75	1.88	0.63	1.98	2.08
(20,20)	0.56	1.74	1.89	0.62	1.98	2.09
(30,30)	0.55	1.68	1.89	0.61	1.92	2.09
(40,40)	0.54	1.68	1.86	0.61	1.91	2.07
(50,50)	0.54	1.65	1.86	0.60	1.88	2.07
(60,60)	0.53	1.63	1.86	0.60	1.86	2.07
(70,70)	0.53	1.63	1.86	0.60	1.86	2.07
(80,80)	0.53	1.63	1.86	0.60	1.86	2.07
(90,90)	0.53	1.62	1.86	0.60	1.86	2.07

Table S1: Continued

	ppRPA@PBE			ppRPA@B3LYP		
	¹ E	¹ A ₁	³ E	¹ E	¹ A ₁	³ E
(100,100)	0.53	1.62	1.86	0.59	1.85	2.07
(110,110)	0.53	1.60	1.86	0.59	1.84	2.07
(120,120)	0.52	1.59	1.86	0.59	1.83	2.07
(130,130)	0.52	1.59	1.86	0.59	1.82	2.07
(140,140)	0.52	1.59	1.86	0.59	1.82	2.07
(150,150)	0.52	1.59	1.86	0.59	1.82	2.07
(160,160)	0.52	1.58	1.86	0.59	1.82	2.07
(170,170)	0.52	1.58	1.86	0.59	1.82	2.07
(180,180)	0.52	1.58	1.87	0.59	1.82	2.07
(190,190)	0.52	1.57	1.87	0.58	1.81	2.07
(191,200)	0.52	1.57	1.87	0.58	1.81	2.07

Table S2: Vertical excitation energies of NV⁻ in diamond obtained from ppRPA@PBE and ppRPA@B3LYP with the supercell model containing 215 atoms. (*O*, *V*) means that *O* occupied orbitals and *V* virtual orbitals were used in the active space. The geometry of the ³A₂ ground state and cc-pVDZ basis set were used. All values are in eV.

	ppRPA@PBE			ppRPA@B3LYP		
	¹ E	¹ A ₁	³ E	¹ E	¹ A ₁	³ E
(10,10)	0.57	1.80	1.97	0.64	2.08	2.13
(20,20)	0.55	1.74	1.96	0.63	2.02	2.12
(30,30)	0.55	1.73	1.94	0.62	2.00	2.10
(40,40)	0.55	1.72	1.93	0.62	2.00	2.10
(50,50)	0.54	1.70	1.93	0.62	1.98	2.10

Table S2: Continued

	ppRPA@PBE			ppRPA@B3LYP		
	¹ E	¹ A ₁	³ E	¹ E	¹ A ₁	³ E
(60,60)	0.54	1.69	1.93	0.61	1.97	2.10
(70,70)	0.54	1.69	1.93	0.61	1.97	2.10
(80,80)	0.54	1.68	1.93	0.61	1.96	2.10
(90,90)	0.53	1.68	1.93	0.61	1.95	2.09
(100,100)	0.53	1.67	1.93	0.61	1.95	2.09
(110,110)	0.53	1.67	1.93	0.61	1.95	2.09
(120,120)	0.53	1.67	1.93	0.61	1.94	2.09
(130,130)	0.53	1.66	1.93	0.61	1.94	2.09
(140,140)	0.53	1.66	1.93	0.61	1.94	2.09
(150,150)	0.53	1.66	1.93	0.61	1.94	2.09
(160,160)	0.53	1.66	1.93	0.61	1.94	2.09
(170,170)	0.53	1.66	1.93	0.60	1.94	2.09
(180,180)	0.53	1.64	1.93	0.60	1.93	2.09
(190,190)	0.52	1.64	1.93	0.60	1.92	2.09
(200,200)	0.52	1.64	1.92	0.60	1.92	2.09

Table S3: Vertical excitation energies of SiV⁰ in diamond obtained from ppRPA@PBE and ppRPA@B3LYP with the supercell model containing 63 atoms. (*O*, *V*) means that *O* occupied orbitals and *V* virtual orbitals were used in the active space. The geometry of the ³A_{2g} ground state and cc-pVDZ basis set were used. All values are in eV.

	ppRPA@PBE			ppRPA@B3LYP		
	³ A _{2u}	³ E _u	³ A _{1u}	³ A _{2u}	³ E _u	³ A _{1u}
(10,10)	1.92	2.09	2.58	2.00	2.18	2.62

Table S3: Continued

	ppRPA@PBE			ppRPA@B3LYP		
	${}^3A_{2u}$	3E_u	${}^3A_{1u}$	${}^3A_{2u}$	3E_u	${}^3A_{1u}$
(20,20)	1.92	2.09	2.57	2.01	2.18	2.66
(30,30)	1.94	2.11	2.54	2.03	2.20	2.63
(40,40)	1.97	2.12	2.51	2.05	2.21	2.61
(50,50)	1.94	2.10	2.48	2.03	2.20	2.58
(60,60)	1.94	2.11	2.47	2.03	2.20	2.57
(70,70)	1.94	2.10	2.47	2.03	2.20	2.56
(80,80)	1.94	2.11	2.47	2.03	2.20	2.56
(90,90)	1.94	2.11	2.46	2.03	2.20	2.56
(100,100)	1.94	2.11	2.46	2.03	2.20	2.56
(110,110)	1.94	2.11	2.46	2.03	2.20	2.56
(120,120)	1.94	2.11	2.46	2.03	2.20	2.55
(130,130)	1.94	2.11	2.46	2.03	2.20	2.55
(140,140)	1.94	2.11	2.46	2.03	2.20	2.55
(150,150)	1.95	2.11	2.46	2.03	2.20	2.55
(160,160)	1.95	2.11	2.46	2.03	2.20	2.55
(170,170)	1.95	2.11	2.46	2.03	2.20	2.55
(180,180)	1.95	2.11	2.46	2.03	2.20	2.55
(190,190)	1.95	2.11	2.46	2.03	2.20	2.55
(194,200)	1.95	2.11	2.46	2.03	2.20	2.55

Table S4: Vertical excitation energies of SiV^0 in diamond obtained from ppRPA@PBE and ppRPA@B3LYP with the supercell model containing 215 atoms. (O , V) means that O occupied orbitals and V virtual orbitals were used in the active space. The geometry of the ${}^3A_{2g}$ ground state and cc-pVDZ basis set were used. All values are in eV.

	ppRPA@PBE			ppRPA@B3LYP		
	${}^3A_{2u}$	3E_u	${}^3A_{1u}$	${}^3A_{2u}$	3E_u	${}^3A_{1u}$
(10,10)	1.52	1.64	2.08	1.59	1.71	2.17
(20,20)	1.52	1.58	2.00	1.59	1.66	2.09
(30,30)	1.51	1.57	1.90	1.57	1.64	1.96
(40,40)	1.51	1.57	1.85	1.58	1.65	1.94
(50,50)	1.50	1.58	1.84	1.57	1.65	1.93
(60,60)	1.49	1.56	1.83	1.55	1.63	1.92
(70,70)	1.47	1.54	1.83	1.54	1.62	1.91
(80,80)	1.47	1.54	1.82	1.54	1.62	1.91
(90,90)	1.47	1.54	1.82	1.54	1.62	1.90
(100,100)	1.47	1.54	1.81	1.54	1.62	1.90
(110,110)	1.47	1.54	1.81	1.54	1.62	1.90
(120,120)	1.47	1.54	1.81	1.54	1.61	1.90
(130,130)	1.47	1.54	1.81	1.54	1.61	1.90
(140,140)	1.47	1.54	1.81	1.54	1.61	1.90
(150,150)	1.47	1.54	1.81	1.54	1.61	1.90
(160,160)	1.47	1.54	1.81	1.54	1.62	1.90
(170,170)	1.47	1.54	1.81	1.54	1.62	1.90
(180,180)	1.47	1.54	1.81	1.54	1.62	1.90
(190,190)	1.47	1.54	1.81	1.54	1.62	1.90
(200,200)	1.47	1.54	1.81	1.54	1.62	1.89

Table S5: Vertical excitation energies of kk - VV^0 in 4H-SiC obtained from ppRPA@PBE and ppRPA@B3LYP with the supercell model containing 215 atoms. (O , V) means that O occupied orbitals and V virtual orbitals were used in the active space. The geometry of the 3A_2 ground state and cc-pVDZ basis set were used. All values are in eV.

	ppRPA@PBE			ppRPA@B3LYP		
	1E	1A_1	3E	1E	1A_1	3E
(10,10)	0.31	1.28	1.10	0.36	1.47	1.18
(20,20)	0.29	0.96	1.15	0.35	1.13	1.17
(30,30)	0.28	0.90	1.14	0.35	1.18	1.30
(40,40)	0.29	0.89	1.16	0.35	1.15	1.27
(50,50)	0.28	0.88	1.13	0.34	1.13	1.27
(60,60)	0.29	0.88	1.12	0.34	1.15	1.24
(70,70)	0.28	0.88	1.14	0.34	1.14	1.23
(80,80)	0.28	0.87	1.12	0.34	1.13	1.23
(90,90)	0.28	0.87	1.12	0.34	1.13	1.24
(100,100)	0.28	0.87	1.12	0.34	1.13	1.24
(110,110)	0.28	0.87	1.12	0.34	1.13	1.24
(120,120)	0.28	0.87	1.12	0.33	1.13	1.23
(130,130)	0.28	0.87	1.12	0.33	1.13	1.24
(140,140)	0.28	0.87	1.12	0.33	1.13	1.24
(150,150)	0.28	0.87	1.12	0.33	1.13	1.24
(160,160)	0.28	0.87	1.12	0.33	1.13	1.24
(170,170)	0.28	0.87	1.12	0.33	1.13	1.24
(180,180)	0.28	0.87	1.12	0.33	1.13	1.24
(190,190)	0.28	0.87	1.12	0.33	1.13	1.24
(200,200)	0.28	0.88	1.12	0.33	1.13	1.23

3 Basis set convergence

Vertical excitation energies of NV^- in diamond obtained from ppRPA@PBE and ppRPA@B3LYP with the cc-pVTZ basis set^{S8} and the supercell model containing 63 atoms are tabulated in Table.S6. It shows that excitation energies obtained from ppRPA with the cc-pVTZ basis set are very similar to those with the cc-pVDZ basis set in Table.S1. Thus, we used cc-pVDZ basis set for ppRPA calculations in this work.

Table S6: Vertical excitation energies of NV^- in diamond obtained from ppRPA@PBE and ppRPA@B3LYP with cc-pVTZ basis set. (O, V) means that O occupied orbitals and V virtual orbitals were used in the active space. The geometry of the 3A_2 ground state and the supercell model containing 63 atoms were used. All values are in eV.

	ppRPA@PBE			ppRPA@B3LYP		
	1E	1A_1	3E	1E	1A_1	3E
(10,10)	0.56	1.74	1.87	0.63	1.98	2.08
(20,20)	0.56	1.74	1.88	0.63	1.97	2.08
(30,30)	0.55	1.68	1.88	0.61	1.91	2.08
(40,40)	0.55	1.68	1.86	0.61	1.91	2.07
(50,50)	0.54	1.65	1.86	0.60	1.88	2.07
(60,60)	0.53	1.63	1.86	0.60	1.86	2.06
(70,70)	0.53	1.63	1.86	0.60	1.86	2.06
(80,80)	0.53	1.62	1.86	0.60	1.86	2.06
(90,90)	0.53	1.62	1.86	0.59	1.85	2.06
(100,100)	0.53	1.62	1.86	0.59	1.85	2.06
(110,110)	0.53	1.60	1.86	0.59	1.83	2.06
(120,120)	0.52	1.59	1.86	0.59	1.83	2.06
(130,130)	0.52	1.59	1.86	0.59	1.82	2.06
(140,140)	0.52	1.58	1.86	0.59	1.82	2.06

Table S6: Continued

	ppRPA@PBE			ppRPA@B3LYP		
	¹ E	¹ A ₁	³ E	¹ E	¹ A ₁	³ E
(150,150)	0.52	1.58	1.86	0.59	1.82	2.06
(160,160)	0.52	1.58	1.86	0.59	1.82	2.06
(170,170)	0.52	1.58	1.86	0.59	1.82	2.06
(180,180)	0.52	1.57	1.86	0.58	1.81	2.06
(190,190)	0.52	1.57	1.86	0.58	1.81	2.06
(200,200)	0.52	1.57	1.86	0.58	1.80	2.06

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